

# DAN217S3

HIGH-SPEED SWITCHING DIODE

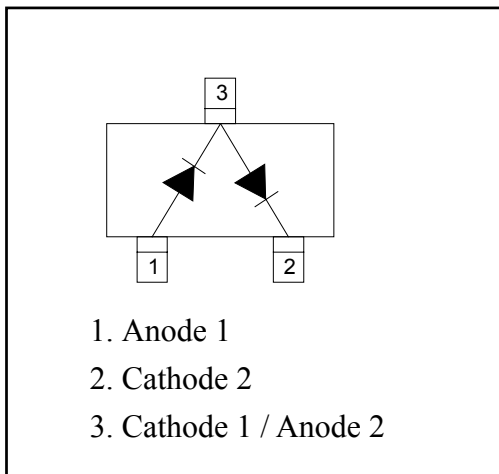
## Description

The DAN217S3 consists of two diodes in a plastic surface mount package. The diodes are connected in series and the unit is designed for high-speed switching application in hybrid thick and thin-film circuits.

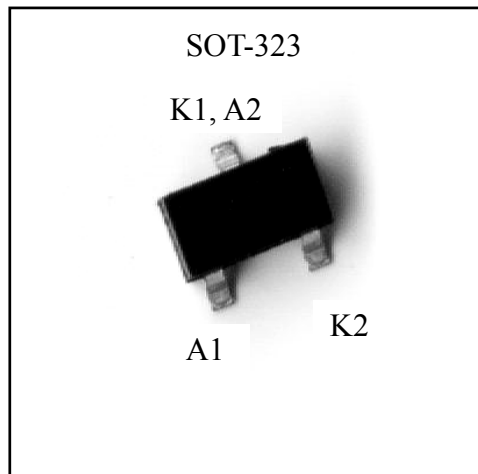
## Features

- Small SMD Package (SOT-323)
- Ultra-high Speed
- Low Forward Voltage
- Fast Reverse Recovery Time

## Equivalent Circuit

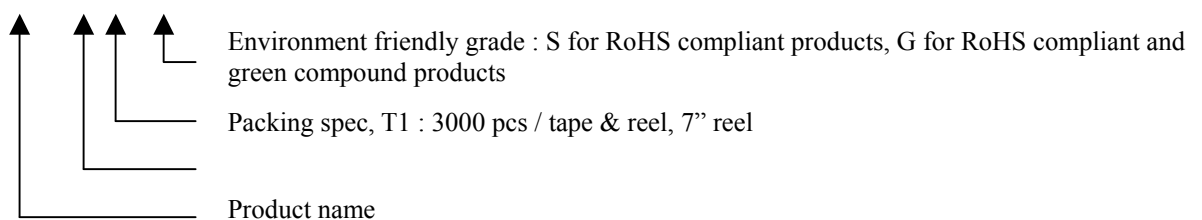


## Outline



## Ordering Information

Device	Package	Shipping
DAN217S3-0-T1-G	SOT-323 (Pb-free lead plating and halogen-free package)	3000 pcs / Tape & Reel



**Absolute Maximum Ratings** @ $T_A=25^{\circ}\text{C}$ , each diode, unless otherwise noted

Parameters	Symbol	Min	Max	Unit
Repetitive peak reverse voltage	$V_{RRM}$	-	110	V
Continuous reverse voltage	$V_R$	-	100	V
Continuous forward current(single diode loaded)	$I_F$	-	215	mA
Continuous forward current(double diode loaded)		-	125	
Repetitive peak forward current	$I_{FRM}$	-	450	mA
Average rectified forward current (Note 1) (averaged over any 20ms period)	$I_{F(AV)}$	-	715	mA
Non-repetitive peak forward current @square wave, $T_j=125^{\circ}\text{C}$ prior to surge	$I_{FSM}$	$t=1\mu\text{s}$	2	A
		$t=1\text{ms}$	1	A
		$t=1\text{s}$	0.5	A
Total power dissipation(Note 1)	$P_{tot}$		200	mW
Operating Junction Temperature Range	$T_j$	-65	+150	$^{\circ}\text{C}$
Storage Temperature Range	$T_{stg}$	-65	+150	$^{\circ}\text{C}$

Note 1: Device mounted on an FR-5 PCB with area measuring  $1.0 \times 0.75 \times 0.062$  in.**Characteristics** ( $T_a=25^{\circ}\text{C}$ )

Characteristic	Symbol	Condition	Min	Max	Unit
Reverse Breakdown Voltage	$V_{(BR)}$	$I_R=100\mu\text{A}$	100	-	V
Forward Voltage	$V_F(1)$	$I_F=1\text{mA}$	-	715	mV
	$V_F(2)$	$I_F=10\text{mA}$	-	855	mV
	$V_F(3)$	$I_F=50\text{mA}$	-	1000	mV
	$V_F(4)$	$I_F=150\text{mA}$	-	1250	mV
Reverse Current	$I_R$	$V_R=100$	-	2.5	$\mu\text{A}$
Total Capacitance	$C_T$	$V_R=0, f=1\text{MHz}$	-	1.5	pF
Reverse Recovery Time	$t_{rr}$	$I_F=I_R=10\text{mA}, R_L=100\Omega$ measured at $I_R=1\text{mA}$	-	6	ns

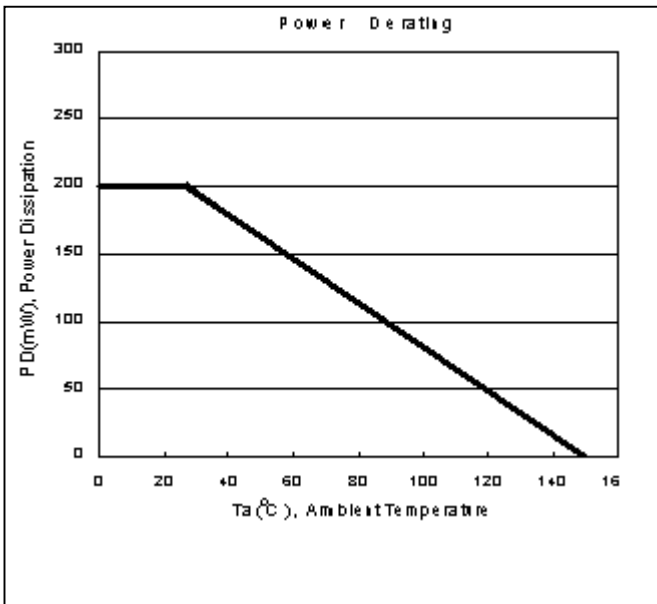
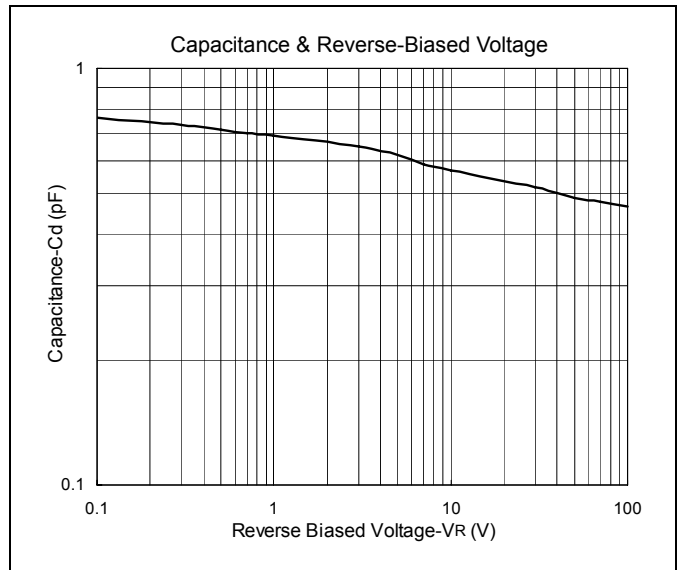
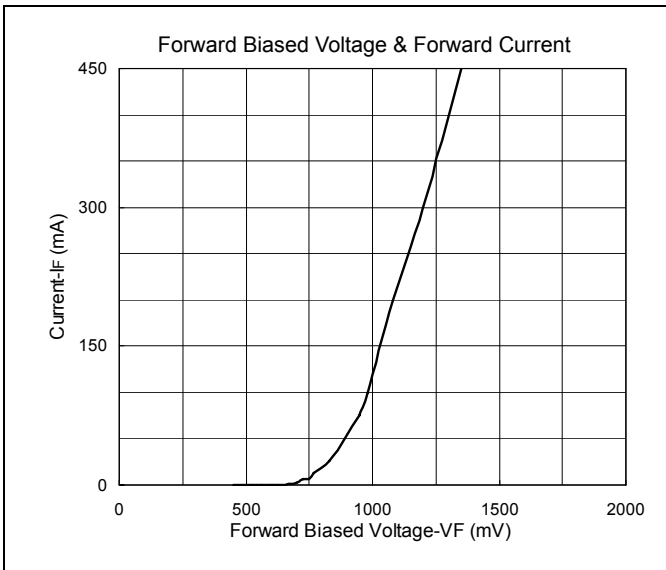
**Thermal Characteristics**

Symbol	Parameter	Conditions	Value	Unit
$R_{th, j-a}$	thermal resistance from junction to ambient	Note 1	625	$^{\circ}\text{C}/\text{W}$

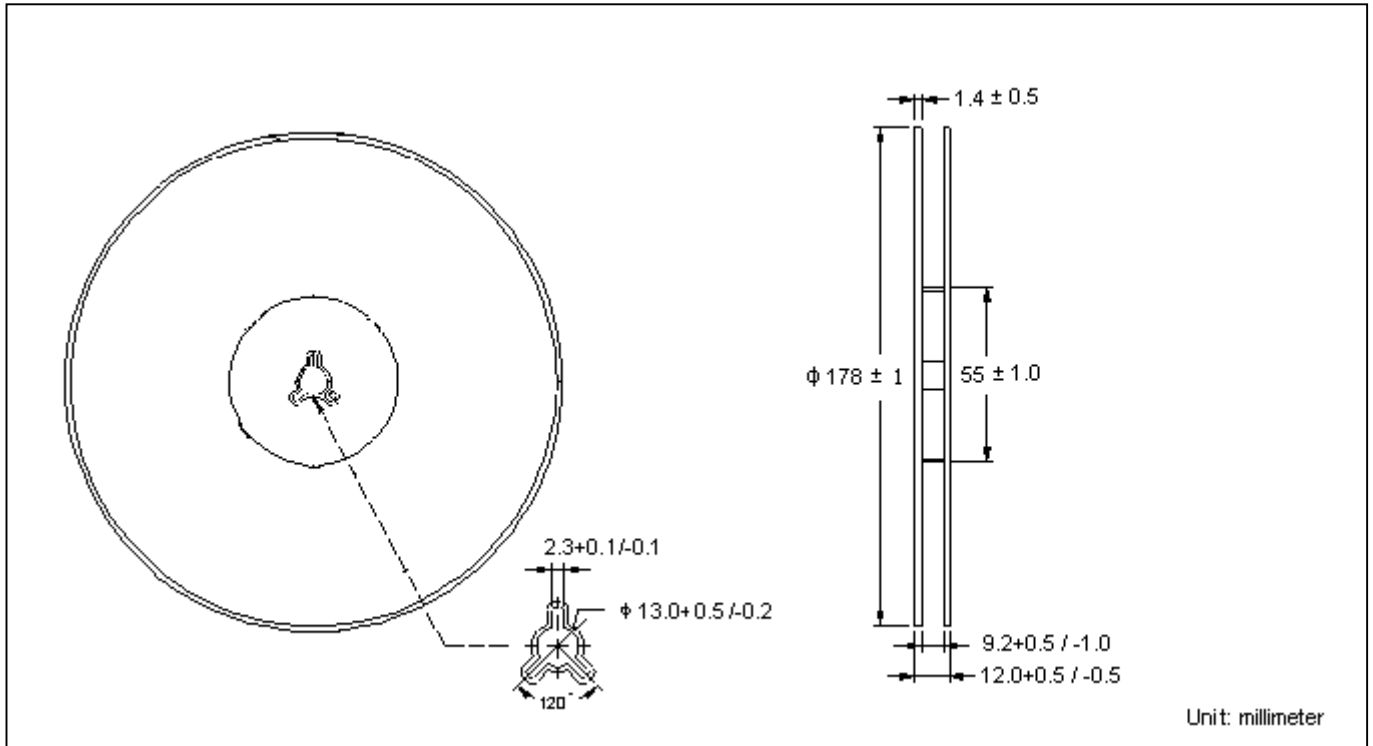
Note 1: Device mounted on an FR-5 PCB with area measuring  $1.0 \times 0.75 \times 0.062$  in.



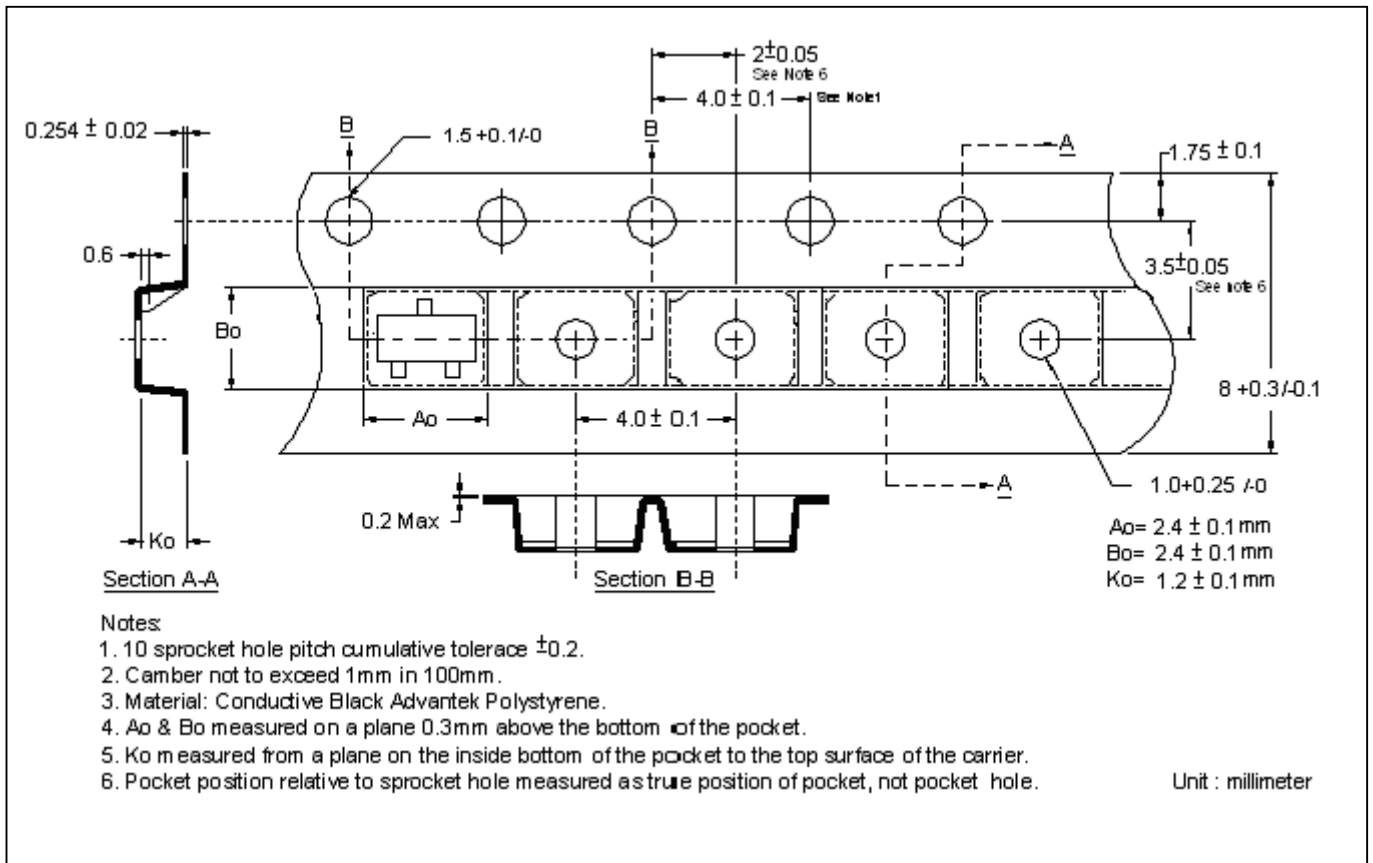
### Typical Characteristics



**Reel Dimension**



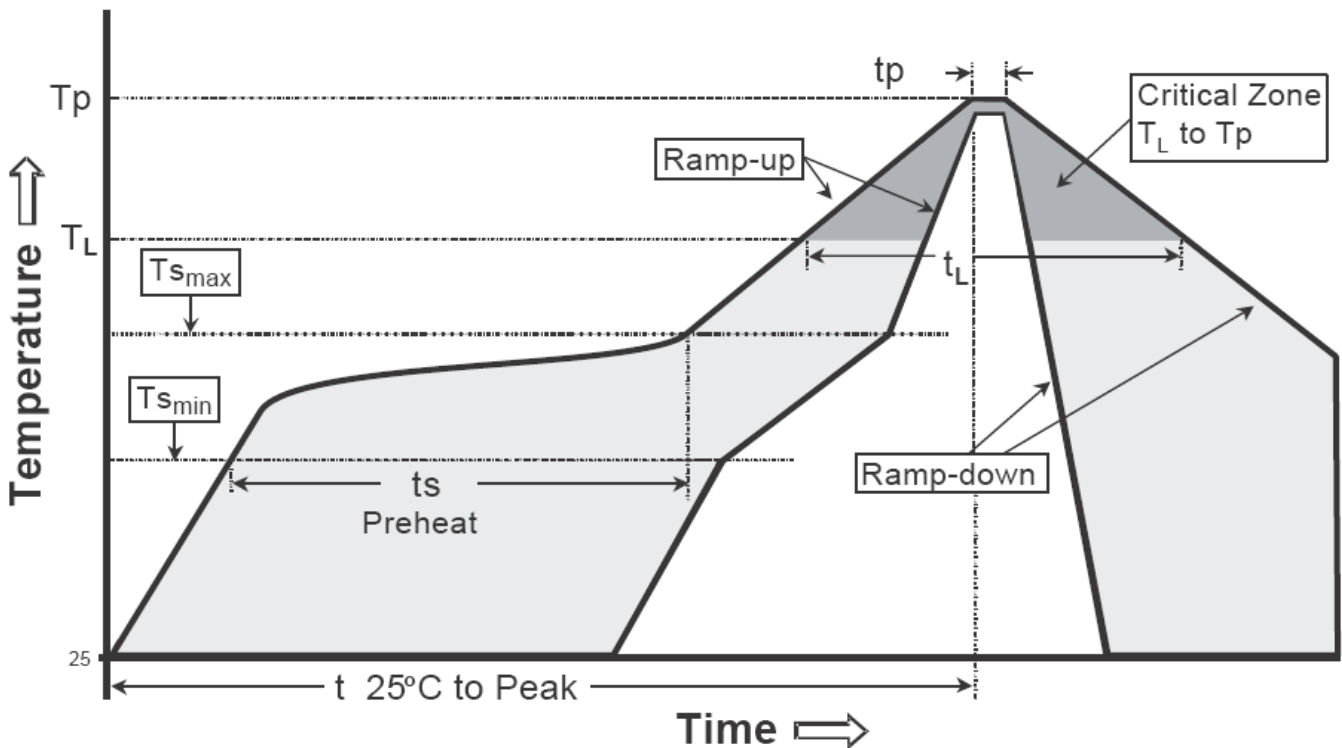
**Carrier Tape Dimension**



**Recommended wave soldering condition**

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

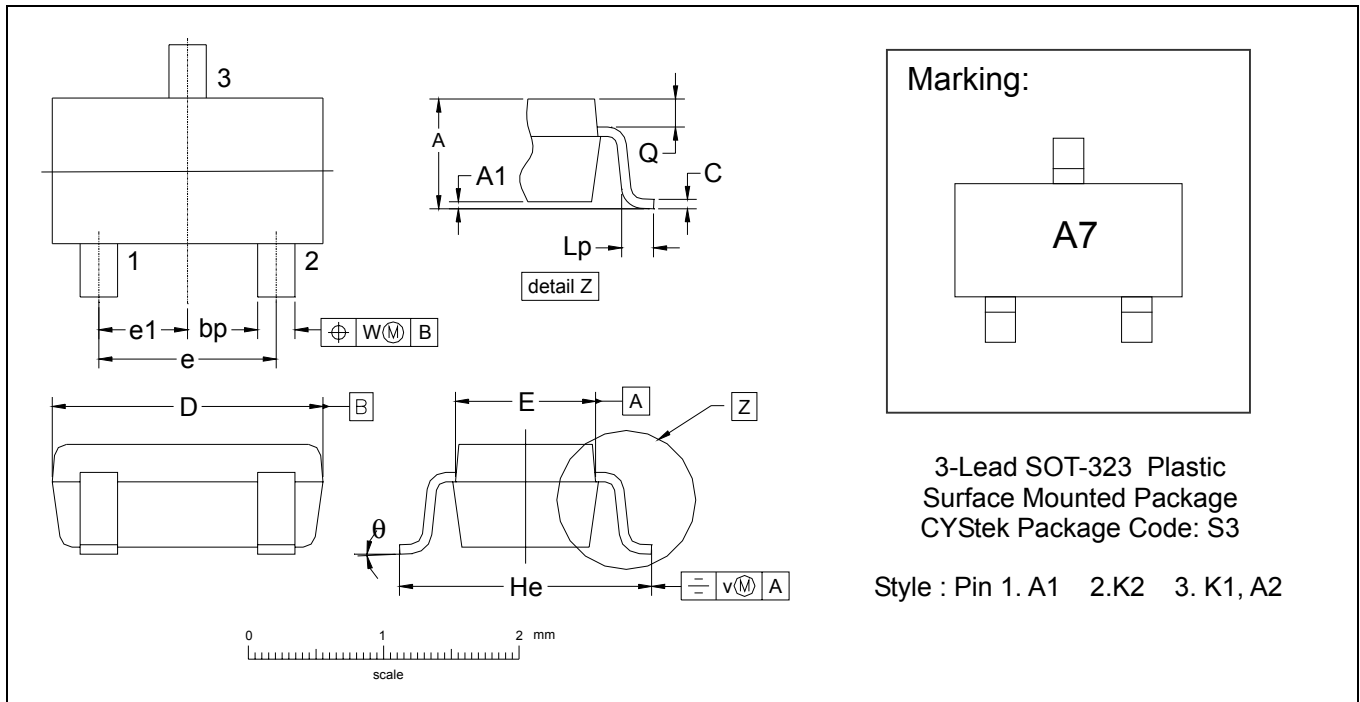
**Recommended temperature profile for IR reflow**



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(Ts min)	100°C	150°C
-Temperature Max(Ts max)	150°C	200°C
-Time(ts min to ts max)	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (Tl)	183°C	217°C
- Time (tL)	60-150 seconds	60-150 seconds
Peak Temperature(Tp)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

**SOT-323 Dimension**



\*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.0315	0.0433	0.80	1.10	e1	0.0256*		0.65*	
A1	0.0000	0.0039	0.00	0.10	He	0.0846	0.0965	2.15	2.45
bp	0.0078	0.0157	0.20	0.40	Lp	0.0105	0.0181	0.26	0.46
C	0.0031	0.0059	0.08	0.15	Q	0.0051	0.0091	0.13	0.23
D	0.0709	0.0866	1.80	2.20	v	0.0079	-	0.2	-
E	0.0453	0.0531	1.15	1.35	w	0.0079	-	0.2	-
e	0.0472	0.0551	1.20	1.40	θ	0°	8°	0°	8°

Notes: 1.Controlling dimension: millimeters.  
 2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.  
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

**Material:**

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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